

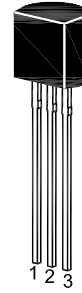
2SA683 / 2SA684

PNP Silicon Epitaxial Planar Transistor

for low frequency power amplification and driver amplification

The transistor is subdivided into three group, Q, R and S according to its DC current gain.

On special request, these transistors can be manufactured in different pin configurations.



1. Emitter 2. Collector 3. Base
TO-92 Plastic Package

Absolute Maximum Ratings ($T_a = 25^\circ\text{C}$)

Parameter	Symbol	Value	Unit
Collector Base Voltage	$-V_{\text{CBO}}$	2SA683 30 2SA684 40	V
Collector Emitter Voltage		2SA683 25 2SA684 30	V
Emitter Base Voltage	$-V_{\text{EBO}}$	5	V
Collector Current	$-I_{\text{C}}$	1	A
Peak Collector Current	$-I_{\text{CP}}$	1.5	A
Collector Power Dissipation	P_{C}	1	W
Junction Temperature	T_{j}	150	$^\circ\text{C}$
Storage Temperature Range	T_{stg}	- 55 to + 150	$^\circ\text{C}$

Characteristics at $T_a = 25^\circ\text{C}$

Parameter	Symbol	Min.	Typ.	Max.	Unit
DC Current Gain	Current Gain Group Q R S h_{FE}	85 120 170 50	- - - -	170 240 340 -	- - - -
at $-V_{\text{CE}} = 10\text{ V}$, $-I_{\text{C}} = 500\text{ mA}$					
at $-V_{\text{CE}} = 5\text{ V}$, $-I_{\text{C}} = 1\text{ A}$					
at $-V_{\text{CE}} = 5\text{ V}$, $-I_{\text{C}} = 1\text{ A}$					
Collector Base Cutoff Current	$-I_{\text{CBO}}$	-	-	100	nA
Collector Base Breakdown Voltage	$-V_{(\text{BR})\text{CBO}}$	2SA683 30 2SA684 40	- -	- -	V
at $-I_{\text{C}} = 10\text{ }\mu\text{A}$					
Collector Emitter Breakdown Voltage	$-V_{(\text{BR})\text{CEO}}$	2SA683 25 2SA684 30	- -	- -	V
at $-I_{\text{C}} = 2\text{ mA}$					
Emitter Base Breakdown Voltage	$-V_{(\text{BR})\text{EBO}}$	5	-	-	V
Collector Emitter Saturation Voltage	$-V_{\text{CE(sat)}}$	-	-	0.4	V
at $-I_{\text{C}} = 500\text{ mA}$, $-I_{\text{B}} = 50\text{ mA}$					
Base Emitter Saturation Voltage	$-V_{\text{BE(sat)}}$	-	-	1.2	V
at $-I_{\text{C}} = 500\text{ mA}$, $-I_{\text{B}} = 50\text{ mA}$					
Transition Frequency	f_{T}	-	200	-	MHz
at $-V_{\text{CB}} = 10\text{ V}$, $I_{\text{E}} = 50\text{ mA}$, $f = 200\text{ MHz}$					
Collector Output Capacitance	C_{ob}	-	-	30	pF
at $-V_{\text{CB}} = 10\text{ V}$, $I_{\text{E}} = 0$, $f = 1\text{ MHz}$					

